TOSHIBA Transistor Silicon NPN Triple Diffused Type

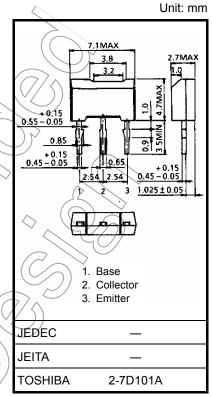
2SC6042

High-Speed, High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High-speed switching: $t_f = 0.2 \mu s$ (max) (IC = 0.3A)
- High breakdown voltage: $V_{CES} = 800 \text{ V}$, $V_{CEO} = 375 \text{ V}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V _{CBO}	800	$(\checkmark\cancel{v}))$
Collector-emitter voltage		V _{CES}	800	*
		V _{CEO}	375	×
Emitter-base voltage		V _{EBO}	780	⇒ v
Collector current	DC	IC	1.0	Α
	Pulse	I _{CP}	2.0	A .
Base current		I _B	0.5	//A
Collector power dissipation	Ta = 25°C	Po	1.0	W
Junction temperature		T	150	°C
Storage temperature range		((T _{stg}))	-55 to 150	\/°C



Weight: 0.2 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

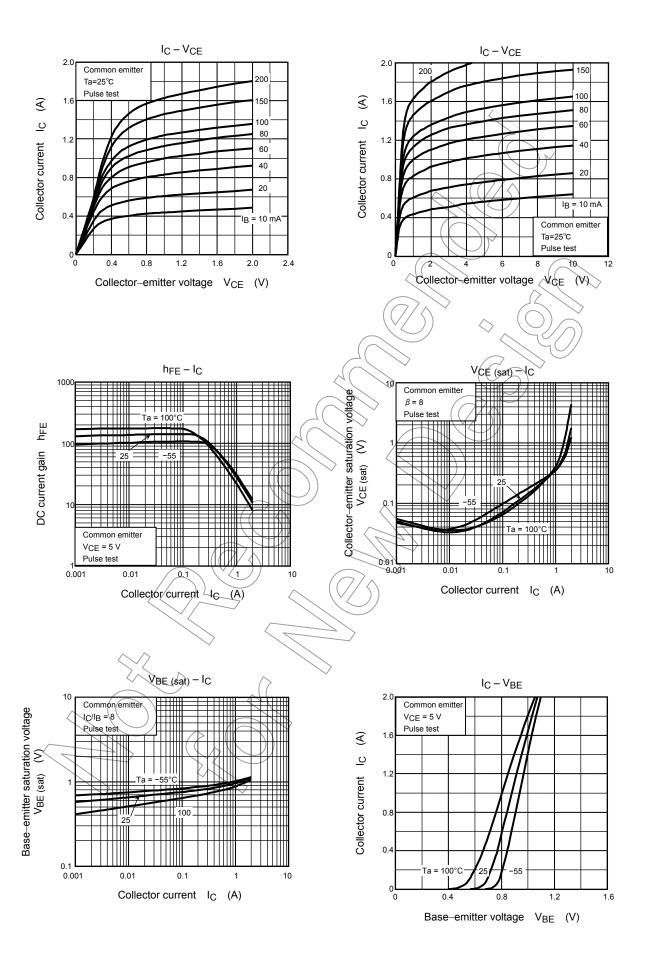
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

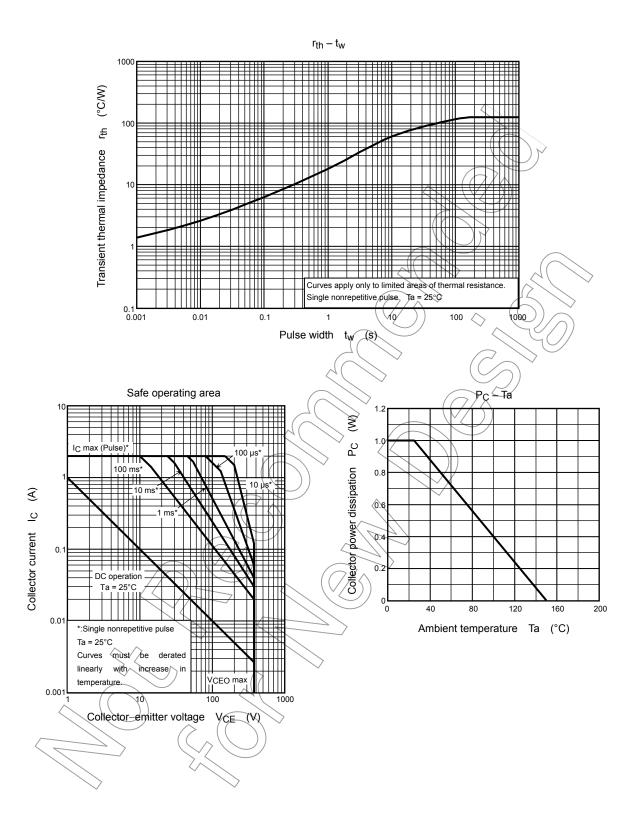
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 800 V, I _E = 0	_	_	100	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	μΑ
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	800	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	375	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA) /-	_	
		h _{FE} (2)	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE} (3)	V _{CE} = 5 V, I _C = 0.2 A	_	_		
Collector emitter saturation voltage		V _{CE} (sat)	I _C = 0.8 A, I _B = 0.1 A	_	_	1.0	V
Base-emitter saturation voltage V _{BE (}		V _{BE} (sat)	I _C = 0.8 A, I _B = 0.1 A	^ —	_	1.3	V
Switching time	Rise time	t _r	20 µs	_		0,5	μs
	Storage time	t _{stg}	IB2 B1 OUT-PUT			4.5	
	Fall time	t _f	I _{B1} = 20 mA, -I _{B2} = 50 mA DUTY CYCLE ≥ 1%	2)	_	0.2	

C6042 Part No. (or abbreviation code) A line indicates lead (Pb)-free package or lead (Pb)-free finish.

2 2006-11-13







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